

# AC08DSMA, AC08FSMA



## DESCRIPTION

The AC08DSMA and AC08FSMA are resin insulation type TRIACs with an effective current of 8 A ( $T_c = 88^\circ\text{C}$ ).

These products are covered with resin mold on the entire case and are electrically insulated with electrodes, giving them a considerable advantage over conventional TRIACs when mounting on a heatsink board or performing high-density mounting.

These products features ratings and electrical characteristics equal to TO-220AB package TRIAC and a high reliability design.

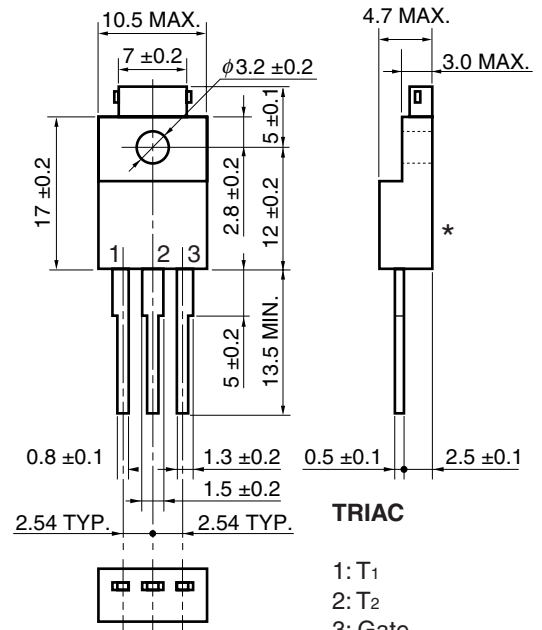
## FEATURES

- Insulation type TRIAC fully covered with resin on the entire case other than electrode leads
- Insulation voltage and conduction equal to conventional mica and polyester film
- Can be replaced with TO-220AB package
- High allowable on-current when using a single unit

## APPLICATIONS

Non-contact switches of motor speed control, heater temperature control, lamp light control

## ★ PACKAGE DRAWING (Unit: mm)



\*:  $T_c$  test bench-mark

Standard weight: 2 g

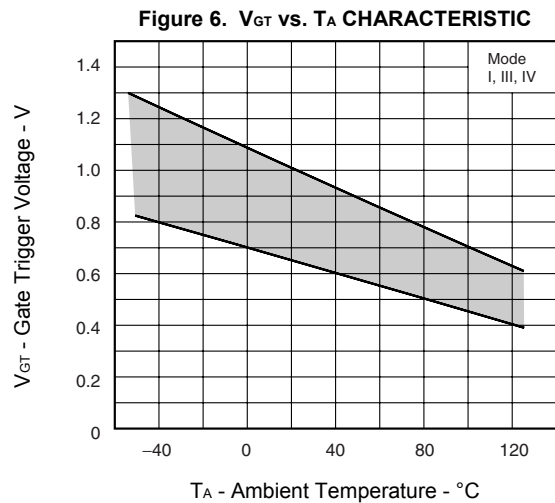
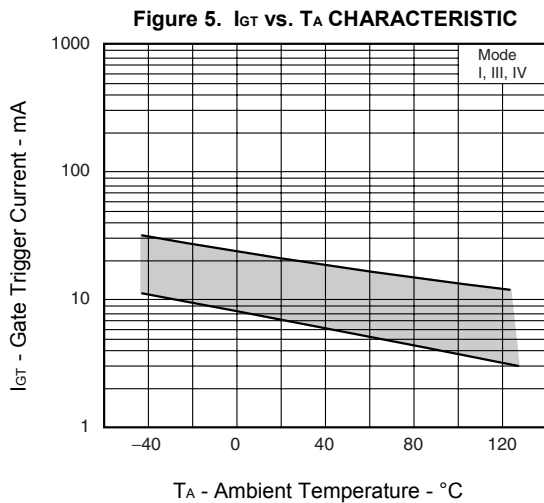
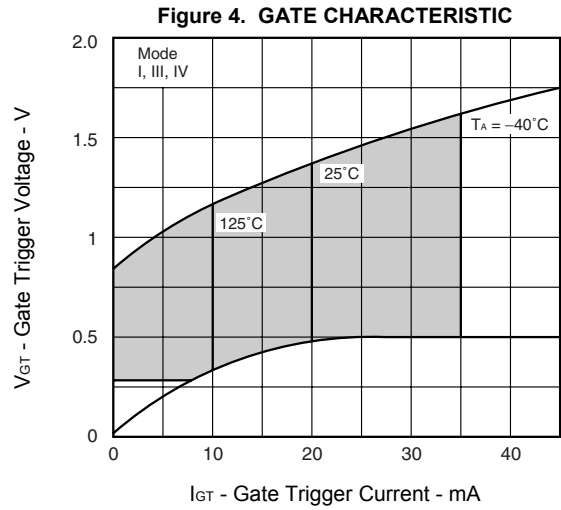
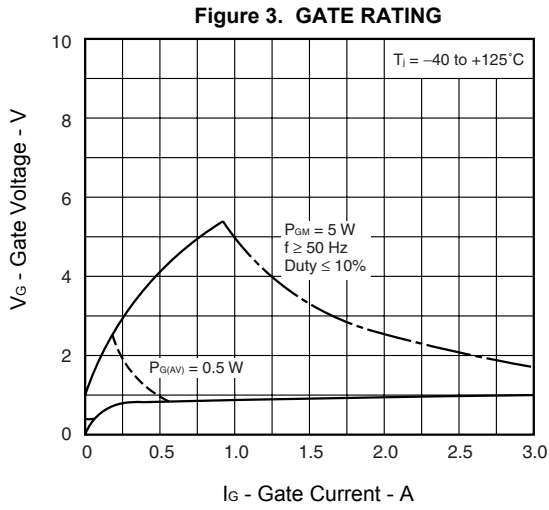
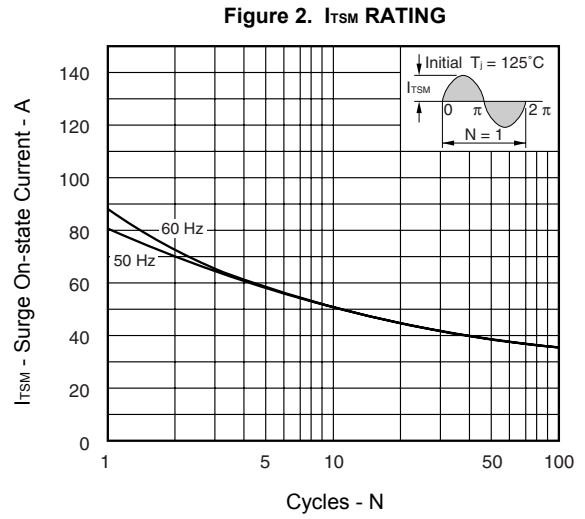
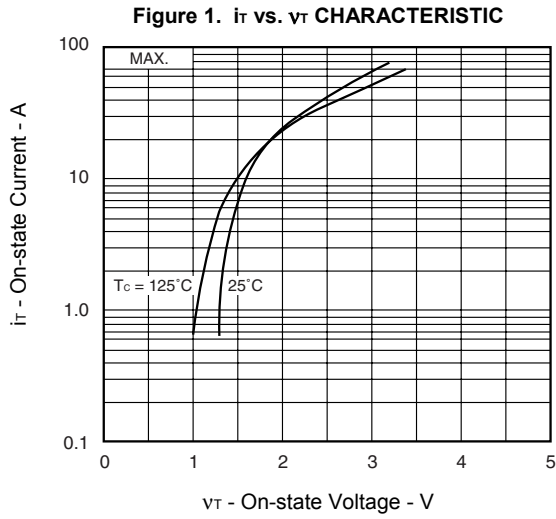
**MAXIMUM RATINGS**

Parameter	Symbol	AC08DSMA	AC08FSMA	Unit	Remarks
Non-repetitive Peak Off-state Voltage	$V_{DSM}$	500	700	V	–
Repetitive Peak Off-state Voltage	$V_{DRM}$	400	600	V	–
Effective On-state Current	$I_{T(RMS)}$	8 ( $T_c = 88^\circ\text{C}$ )		A	Refer to <b>Figure 11</b> and <b>12</b> .
Surge On-state Current	$I_{TSM}$	80 (50 Hz 1 cycle) 88 (60 Hz 1 cycle)		A	Refer to <b>Figure 2</b> .
Fusing Current	$\int i_T^2 dt$	28 ( $1\text{ ms} \leq t \leq 10\text{ ms}$ )		$\text{A}^2\text{s}$	–
Critical Rate Rise of On-state Current	$di_T/dt$	50		$\text{A}/\mu\text{s}$	–
Peak Gate Power Dissipation	$P_{GM}$	5.0 ( $f \geq 50\text{ Hz}$ , Duty $\leq 10\%$ )		W	–
Average Gate Power Dissipation	$P_{G(AV)}$	0.5		W	–
Peak Gate Current	$I_{GM}$	$\pm 3$ ( $f \geq 50\text{ Hz}$ , Duty $\leq 10\%$ )		A	–
Junction Temperature	$T_j$	–40~+125		$^\circ\text{C}$	–
Storage Temperature	$T_{stg}$	–55~+150		$^\circ\text{C}$	–

**ELECTRICAL CHARACTERISTICS ( $T_j = 25^\circ\text{C}$ )**

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	Remarks	
Repetitive Peak Off-state Current		$I_{DRM}$	$V_{DM} = V_{DRM}$	$T_j = 25^\circ\text{C}$	–	–	100	$\mu\text{A}$	–
				$T_j = 125^\circ\text{C}$	–	–	2	mA	–
On-state Voltage		$V_{TM}$	$I_{TM} = 10\text{ A}$	–	–	1.6	V	Refer to <b>Figure 1</b> .	
Gate Trigger Current	Mode I	$I_{GT}$	$V_{DM} = 12\text{ V}$ , $R_L = 30\ \Omega$	$T_{2+}, G+$	–	–	20	mA	Refer to <b>Figure 4</b> .
	II			$T_{2-}, G+$	–	–	–		
	III			$T_{2-}, G-$	–	–	20		
	IV			$T_{2+}, G-$	–	–	20		
Gate Trigger Voltage	Mode I	$V_{GT}$	$V_{DM} = 12\text{ V}$ , $R_L = 30\ \Omega$	$T_{2+}, G+$	–	–	1.5	V	Refer to <b>Figure 4</b> .
	II			$T_{2-}, G+$	–	–	–		
	III			$T_{2-}, G-$	–	–	1.5		
	IV			$T_{2+}, G-$	–	–	1.5		
Gate Non-trigger Voltage		$V_{GD}$	$T_j = 125^\circ\text{C}$ , $V_{DM} = \frac{1}{2} V_{DRM}$	0.3	–	–	V	–	
★ Holding Current		$I_H$	$V_{DM} = 24\text{ V}$ , $I_{TM} = 10\text{ A}$	–	30	–	mA	–	
Critical Rate Rise of Off-state Voltage		$dv/dt$	$T_j = 125^\circ\text{C}$ , $V_{DM} = \frac{2}{3} V_{DRM}$	–	100	–	$\text{V}/\mu\text{s}$	–	
Commutating Critical Rate Rise of Off-state Voltage		$(dv/dt)_c$	$T_j = 125^\circ\text{C}$ , $(di_T/dt)_c = -4\text{ A/ms}$ , $V_D = 400\text{ V}$	10	–	–	$\text{V}/\mu\text{s}$	–	
Thermal Resistance <sup>Note</sup>		$R_{th(j-c)}$	Junction-to-case AC	–	–	3.7	$^\circ\text{C}/\text{W}$	Refer to <b>Figure 13</b> .	

TYPICAL CHARACTERISTICS



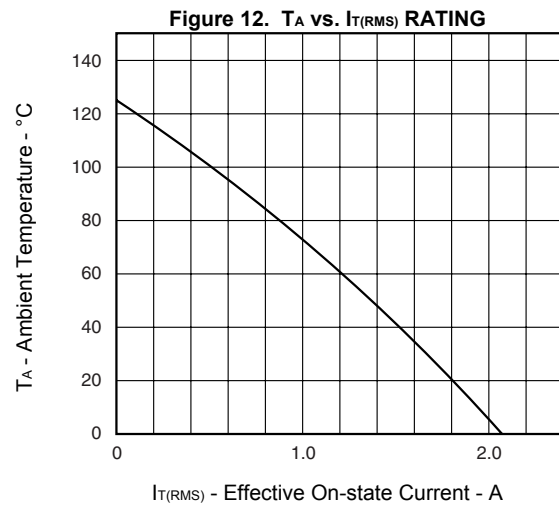
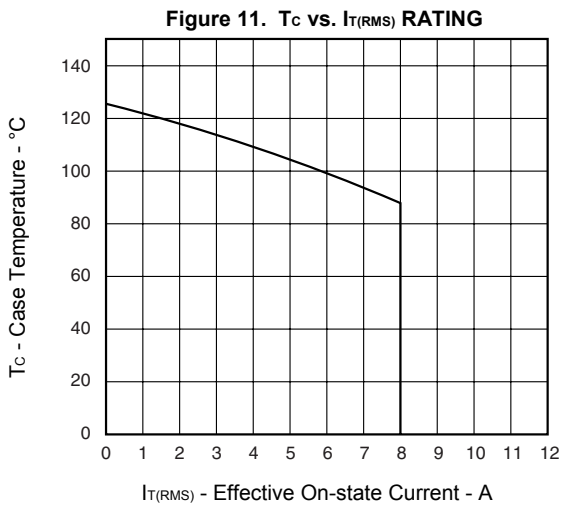
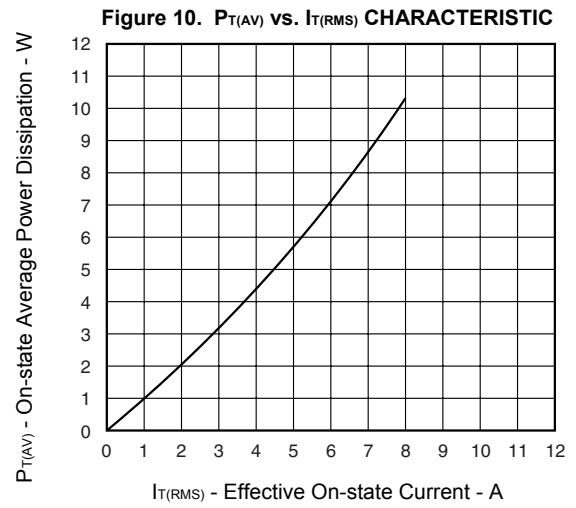
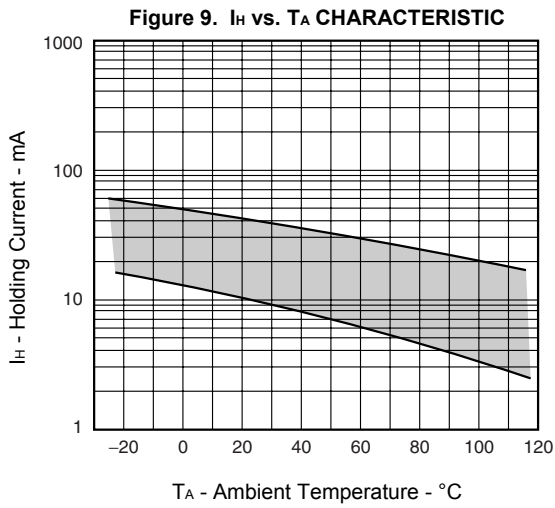
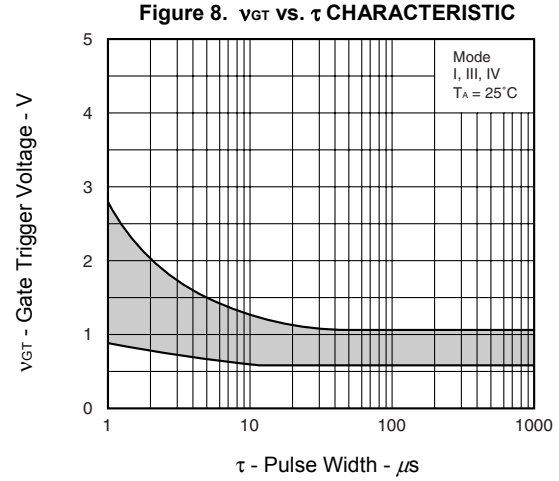
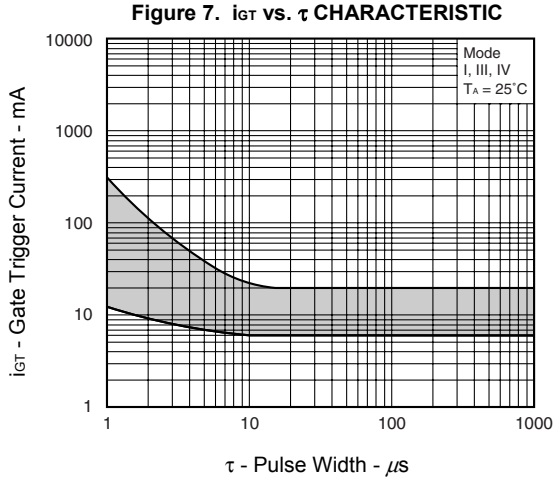


Figure 13.  $Z_{th}$  CHARACTERISTIC

